



APPLICATION DATA SHEET

Electronic Version v14

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Title of Invention	HIGH-PERFORMANCE CMOS SOI DEVICES ON HYBRID CRYSTAL-ORIENTED SUBSTRATES		
Application Type : regular, utility Attorney Docket Number : BUR920030159US1			
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Attorney Information: practitioner(s) at Customer Number: 29154  as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.			

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